**Vishay Semiconductors** 

# High Performance Schottky Rectifier, 3.5 A



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D-PAK (TO-252

<b>–</b>	
01	03
Anode	Anode

PRODUCT SUMMARY								
Package	D-PAK (TO-252AA)							
I <sub>F(AV)</sub>	3.5 A							
V <sub>R</sub>	40 V							
V <sub>F</sub> at I <sub>F</sub>	See Electrical table							
I <sub>RM</sub>	24 mA at 125 °C							
T <sub>J</sub> max.	150 °C							
Diode variation	Single die							
E <sub>AS</sub>	8 mJ							

### **FEATURES**

- Low forward voltage drop
- Guard ring for enhanced ruggedness and long **RoHS** term reliability COMPLIANT HALOGEN
- Popular D-PAK outline
- · Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### DESCRIPTION

The VS-30WQ04FN-M3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS								
I <sub>F(AV)</sub>	Rectangular waveform	3.5	А						
V <sub>RRM</sub>		40	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	500	А						
V <sub>F</sub>	3 A <sub>pk</sub> , T <sub>J</sub> = 125 °C	0.49	V						
TJ		-40 to +150	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-30WQ04FN-M3	UNITS					
Maximum DC reverse voltage	V <sub>R</sub>	40	V					
Maximum working peak reverse voltage	V <sub>RWM</sub>	40	v					

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST COND	TEST CONDITIONS						
Maximum average forward current See fig. 5	I <sub>F(AV)</sub>	50 % duty cycle at T <sub>C</sub> = 135 °C	3.5						
Maximum peak one cycle non-repetitive	1	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with rated	500	А				
surge current. See fig. 7	I <sub>FSM</sub>	10 ms sine or 6 ms rect. pulse	V <sub>RRM</sub> applied	80					
Non-repetitive avalanche energy	E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 16 m⊦	8.0	mJ					
Repetitive avalanche current	I <sub>AR</sub>	Current decaying linearly to zero Frequency limited by $T_J$ maximum	1.0	А					

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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	TEST CONDITIONS					
Maximum forward voltage drop See fig. 1		3 A	T. = 25 °C	0.53	V			
	V <sub>FM</sub> <sup>(1)</sup>	6 A	1j=23 0	0.67				
	¥FM (")	3 A	T. = 125 °C	0.49				
		6 A	1j = 125 C	0.62				
Maximum reverse leakage current	I <sub>RM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B} = Rated V_{\rm B}$	2				
See fig. 2		T <sub>J</sub> = 125 °C	$v_{\rm R} = naleu v_{\rm R}$	24	mA			
Threshold voltage	V <sub>F(TO)</sub>			0.34	V			
Forward slope resistance	r <sub>t</sub>	T <sub>J</sub> = T <sub>J</sub> maximum		37.33	mΩ			
Typical junction capacitance	CT	$V_R = 5 V_{DC}$ (test signal ran	189	pF				
Typical series inductance	Ls	Measured lead to lead 5 m	5.0	nH				
Maximum voltage rate of change	dV/dt	Rated V <sub>R</sub>	10 000	V/µs				

#### Note

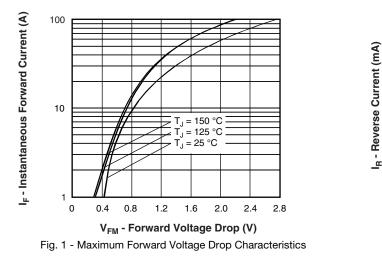
 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum junction and storage temperature range	T <sub>J</sub> <sup>(1)</sup> , T <sub>Stg</sub>		-40 to +150	°C					
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation See fig. 4	4.7	°C/W					
Approvimate weight			0.3	g					
Approximate weight			0.01	oz.					
Marking device		Case style D-PAK (similar to TO-252AA)	30WQ04FN						

#### Note

(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink

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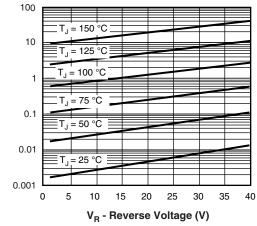


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

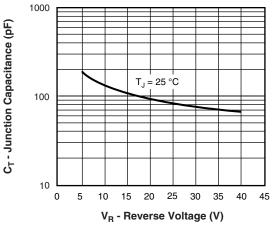


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

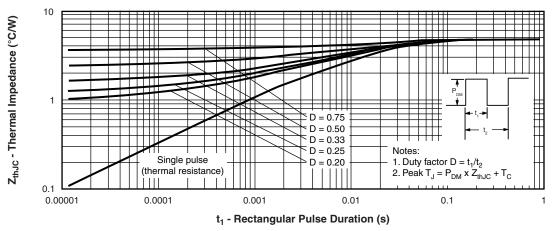
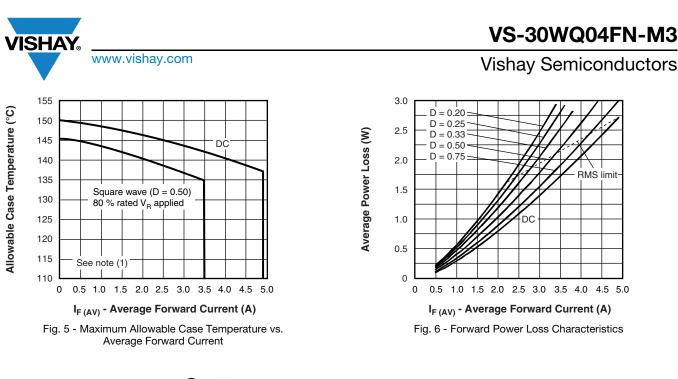
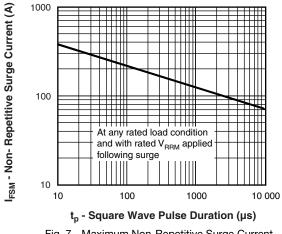


Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics





#### Fig. 7 - Maximum Non-Repetitive Surge Current

#### Note

(1) Formula used:  $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$ ;  $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$ 

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### **ORDERING INFORMATION TABLE**

Device code	VS-	30	W	Q	04	FN	TRL	-M3	
	1	2	3	4	5	6	7	8	
	1 -	· Visl	nay Sen	niconduc	ctors pro	oduct			
	2 - Current rating (3.5 A)								
	3 - Package identifier:								
		W =	D-PAK						
	4 -	· Sch	ottky "C	" series					
	5 -	Vol	age rati	ng (04 =	= 40 V)				
	6 -	- FN	= TO-28	52AA (D	-PAK)				
	7 -	• N	one = tu	lbe					
	• TR = tape and reel								
		<ul> <li>TRL = tape and reel (left oriented)</li> </ul>							
		<ul> <li>TRR = tape and reel (right oriented)</li> </ul>							
	8 -	· Env	rironmer	ntal digit	:				
				~		12			

-M3 = halogen-free, RoHS-compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-30WQ04FN-M3	75	3000	Antistatic plastic tube						
VS-30WQ04FNTR-M3	2000	2000	13" diameter reel						
VS-30WQ04FNTRL-M3	3000	3000	13" diameter reel						
VS-30WQ04FNTRR-M3	3000	3000	13" diameter reel						

LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?95627							
Part marking information	www.vishay.com/doc?95176						
Packaging information	www.vishay.com/doc?95033						
SPICE model	www.vishay.com/doc?95288						
	www.vishay.com/doc?95630						





D-PAK (TO-252AA) "M"

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INCHES		NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

(4) Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-252AA



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